

# AC Input Phototransistor Small Outline Surface Mount Optocoupler

The MOC256 is an AC input phototransistor optocoupler. The device consists of two infrared emitters connected in anti–parallel and coupled to a silicon NPN phototransistor detector. They are designed for applications requiring the detection or monitoring of AC signals. These devices are constructed with a standard SOIC–8 footprint.

- Guaranteed Current Transfer Ratio CTR of 20% at I<sub>F</sub>=10 mA
- UL Recognized. File Number E90700, Volume 2
- Industry Standard SOIC-8 Surface Mountable Package
- Standard Lead Spacing of 0.050 inches
- · Available in Tape and Reel Option
- Bidirectional AC Input (Protection Against Reversed DC Bias)
- Guaranteed CTR Symmetry of 2:1 Maximum
- High Input-Output Isolation of 3000 Vac (rms) Guaranteed

### **MAXIMUM RATINGS** (T<sub>A</sub> = 25°C unless otherwise noted)

Rating		Value	Unit				
INPUT LED							
Forward Current — Continuous	ΙF	60	mA				
Forward Current — Peak (PW = 100 μs, 120 pps)	IF(pk)	1	Α				
Reverse Voltage	٧R	6	V				
LED Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	90 0.8	mW mW/°C				

### **OUTPUT TRANSISTOR**

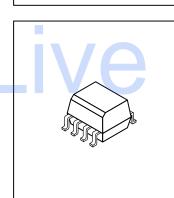
Collector–Emitter Voltage	VCEO	30	V
Emitter-Base Voltage	VECO	7	V
Collector Current — Continuous	IC	150	mA
Detector Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	150 1.76	mW mW/°C

### **TOTAL DEVICE**

Input-Output Isolation Voltage <sup>(1)</sup> (60 Hz, 1 sec Duration)	VISO	3000	Vac(rms)
Total Device Power Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	PD	250 2.94	mW mW/°C
Ambient Operating Temperature Range(2)	T <sub>A</sub>	-45 to +100	°C
Storage Temperature Range(2)	T <sub>stg</sub>	-45 to +125	°C
Lead Soldering Temperature (10 sec, 1/16" from case)	_	260	°C

MOC256

SMALL OUTLINE OPTOISOLATORS AC INPUT TRANSISTOR OUTPUT



# SCHEMATIC 10 08 20 77 30 66 40 55 PIN 1. AC IN 2. AC IN 3. N.C. 4. N.C. 5. EMITTER 6. COLLECTOR 7. BASE

8. N.C.

<sup>1.</sup> Input—output isolation voltage is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 5, 6 and 7 are common.



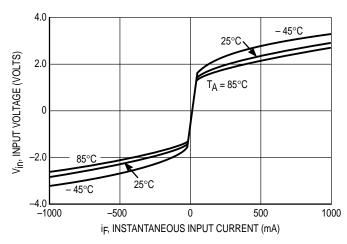
# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)(1)

Characteristic	Symbol	Min	Typ <sup>(1)</sup>	Max	Unit
NPUT LED	•				
Forward Voltage (I <sub>F</sub> = 10 mA, both direction)	VF	_	1.15	1.5	Volts
Capacitance (V = 0 V, f = 1 MHz)	CJ	_	20	_	pF
OUTPUT TRANSISTOR	•	•			•
Collector–Emitter Dark Current (V <sub>CE</sub> = 10 V)	ICEO	_	1	100	nA
$T_A = 100^{\circ}C$		_	1	_	μΑ
Collector–Base Dark Current (V <sub>CB</sub> = 10 V)	ІСВО	_	0.2	_	nA
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 10 mA)	V(BR)CEO	30	45	_	Volts
Collector–Base Breakdown Voltage (I <sub>C</sub> = 100 μA)	V(BR)CBO	70	100	_	Volts
Emitter–Collector Breakdown Voltage (I <sub>E</sub> = 100 μA)	V(BR)ECO	5	7.8	_	Volts
DC Current Gain (I <sub>C</sub> = 2 mA, V <sub>CE</sub> = 5 V)	hFE	_	500	_	-
Collector–Emitter Capacitance (f = 1 MHz, V <sub>CE</sub> = 0 V)	C <sub>CE</sub>	_	7	_	pF
Collector–Base Capacitance (f = 1 MHz, V <sub>CB</sub> = 0 V)	ССВ	_	20	_	pF
Emitter-Base Capacitance (f = 1 MHz, V <sub>EB</sub> = 0 V)	C <sub>EB</sub>	_	10	_	pF
COUPLED					
Output Collector Current (IF = $\pm$ 10 mA, V <sub>CE</sub> = 10 V)	I <sub>C</sub> (CTR) <sup>(5)</sup>	2 (20)	15 (150)	_	mA (%)
Output Collector Current Symmetry(3) $ \left( \frac{I_{C} \text{ at } I_{F} = +10 \text{ mA}, V_{CE} = 10 \text{ V}}{I_{C} \text{ at } I_{F} = -10 \text{ mA}, V_{CE} = 10 \text{ V}} \right) $	_	0.5	1.0	2.0	_
Collector–Emitter Saturation Voltage ( $I_C = 0.5 \text{ mA}, I_F = \pm 10 \text{ mA}$ )	VCE(sat)	_	0.1	0.4	Volts
Input-Output Isolation Voltage (f = 60 Hz, t = 1 sec)(4,5)	Viso	3000	_	_	Vac(rms)
Isolation Resistance (V = 500 V)(5)	R <sub>ISO</sub>	10 <sup>11</sup>	_	_	Ω
Isolation Capacitance (V = 0 V, f = 1 MHz)(5)	C <sub>ISO</sub>	_	0.2	_	pF

- 1. Always design to the specified minimum/maximum electrical limits (where applicable).
- 2. Current Transfer Ratio (CTR) =  $I_C/I_F \times 100\%$ .
- 3. This specification guarantees that the higher of the two  $I_C$  readings will be no more than 3 times the lower at  $I_F = 10$  mA. 4. Input–Output Isolation Voltage,  $V_{ISO}$ , is an internal device dielectric breakdown rating.
- 5. For this test, pins 1 and 2 are common, and pins 5, 6 and 7 are common.



### **TYPICAL CHARACTERISTICS**



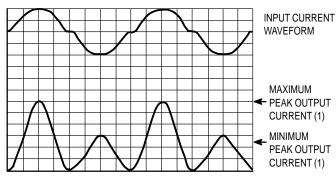
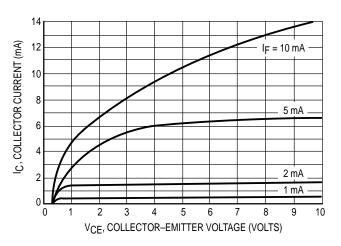


Figure 1. Input Voltage versus Input Current

Figure 2. Output Characteristics



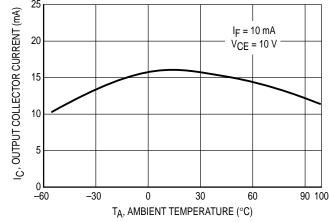
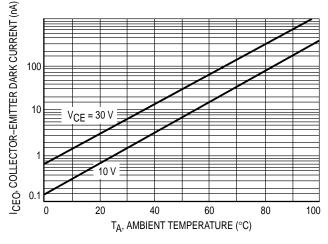


Figure 3. Collector Current versus Collector–Emitter Voltage

Figure 4. Output Current versus Ambient Temperature



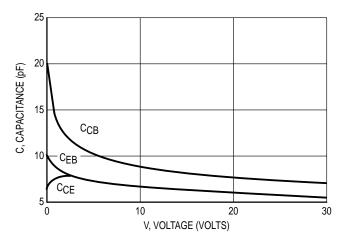
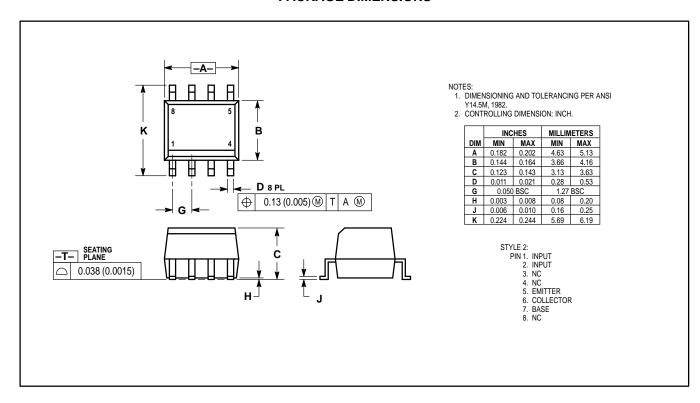


Figure 5. Dark Current versus Ambient Temperature

Figure 6. Capacitances versus Voltage



### **PACKAGE DIMENSIONS**





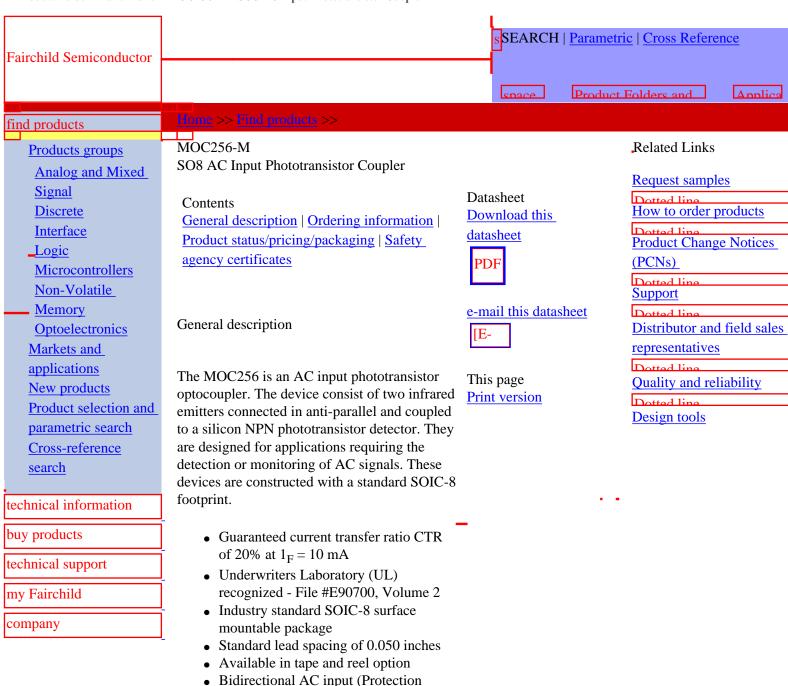
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against reversed DC bias)Guaranteed CTR symmetry of 2:1

Vac (RMS) guaranteed

• High input - Output isolation of 3000

maximum

# Ordering information

The following options can be ordered with this part:

Option	Order Entry Identifier	Description
R1	Surface-Mount Lead Bend Tape and Reel (500-pc reel)	
R2	R2	Surface-Mount Lead Bend Tape and Reel (2500-pc reel)

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Product status/pricing/packaging

Product	<b>Product status</b>	Pricing*	Package type	Leads	Packing method
MOC256-M	Full Production	\$0.334	SOIC	8	RAIL
MOC256R1-M	Full Production	\$0.344	SOIC	8	TAPE REEL
MOC256R2-M	Full Production	\$0.344	SOIC	8	TAPE REEL

<sup>\* 1,000</sup> piece Budgetary Pricing

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Safety agency certificates

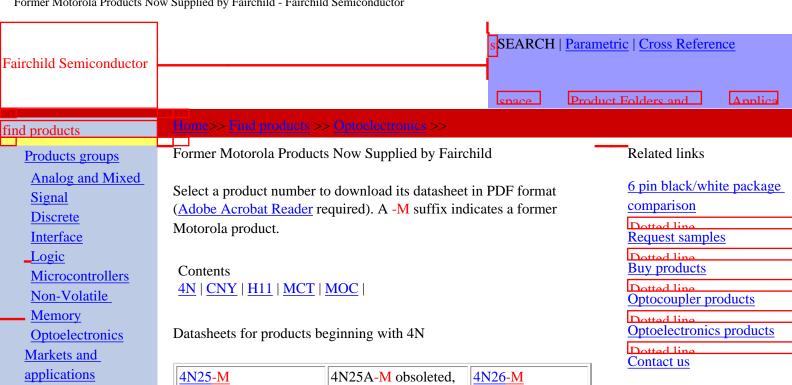
Cetificate		Agency		
<u>8460,8461</u> (171 K)	BSI	British Standards Institution		
<u>136616</u> (161 K)	VDE	VDE Pruf-und Zertifizierungsinstitut		
E90700, Vol. 2 (254 K)	UL	Underwriters Laboratories Inc.		

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4N25-M	4N25A-M obsoleted, no replacement	4N26-M
4N27-M	4N28-M	4N29-M replaced by 4N29
4N29A-M replaced by 4N29	4N30-M replaced by 4N30	4N31-M replaced by 4N31
4N32-M replaced by 4N32	4N33-M replaced by 4N33	4N35-M
4N36-M	4N37-M	4N38-M replaced by 4N38
4N38A-M replaced by 4N38		

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Datasheets for products beginning with H11

<u>H11A1-M</u>	H11AA1-M replaced by H11AA1	H11AA2-M replaced by H11AA2

H11AA3-M replaced by H11AA3	H11AA4-M replaced by H11AA4	<u>H11AV1-M</u>
H11AV1A-M	H11AV2-M	H11AV2A-M
H11B1-M replaced by H11B1	H11B3-M replaced by H11B3	H11D1-M replaced by H11D1
H11D2-M replaced by H11D2	H11G1-M replaced by H11G1	H11G2-M replaced by H11G2
H11G3-M replaced by H11G3	H11L1-M	H11L2-M
H11L3-M		

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# Datasheets for products beginning with MCT

MCT2-M	MCT2E-M	

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# Datasheets for products beginning with MOC

MOC205 M	MOCOOC M	MOC207 M
<u>MOC205-M</u>	<u>MOC206-M</u>	<u>MOC207-M</u>
MOC208-M	MOC211-M	MOC212-M
MOC213-M	MOC215-M	MOC216-M
MOC217-M	<u>MOC223-M</u>	MOC256-M
MOC3010-M	MOC3011-M	MOC3012-M
MOC3020-M	MOC3021-M	MOC3022-M
MOC3023-M	MOC3031-M	MOC3032-M
MOC3033-M	MOC3041-M	MOC3042-M
MOC3043-M	MOC3051-M	MOC3052-M
MOC3061-M	MOC3062-M	MOC3063-M
MOC3081-M	MOC3081-M	MOC3083-M
MOC3162-M	MOC3163-M	MOC5007-M
MOC5008-M	MOC5009-M	MOC8030-M replaced by MOC8030

Former Motorola Products Now Supplied by Fairchild - Fairchild Semiconductor

MOC8050-M replaced by MOC8050	MOC8080-M replaced by MOC8080	MOC8100-M
MOC8204-M replaced by MOC8204	MOCD207-M	MOCD208-M
MOCD211-M	MOCD213-M	MOCD217-M
MOCD223-M		

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-Last updated: March 19, 2002